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## FQB9N50C

# N-Channel QFET<sup>®</sup> MOSFET 500 V, 9 A, 800 m $\Omega$

## Features

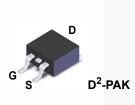
- + 9 A, 500 V,  $R_{DS(on)}$  = 800 m $\Omega\,$  (Max.) @ V\_{GS} = 10 V, I\_D = 4.5 A
- Low Gate Charge (Typ. 28 nC)
- Low Crss (Typ. 24 pF)
- 100% Avalanche Tested

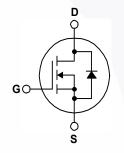
### November 2013

FQB9N50C — N-Channel QFET<sup>®</sup> MOSFET

## Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter		FQB9N50CTM	Unit
V <sub>DSS</sub>	Drain-Source Voltage		500	V
I <sub>D</sub>	Drain Current - Continuous ( $T_c = 25^{\circ}C$ )		9	А
	- Continuous (T <sub>C</sub> = 100°C)		5.4	А
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	36	A
V <sub>GSS</sub>	Gate-Source Voltage		± 30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		360	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1)	9	A
E <sub>AR</sub>	Repetitive Avalanche Energy (No		13.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
P <sub>D</sub>	Power Dissipation ( $T_C = 25^{\circ}C$ )		135	W
	- Derate above 25°C		1.07	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes,		300	°C
'L	1/8" from case for 5 seconds		500	

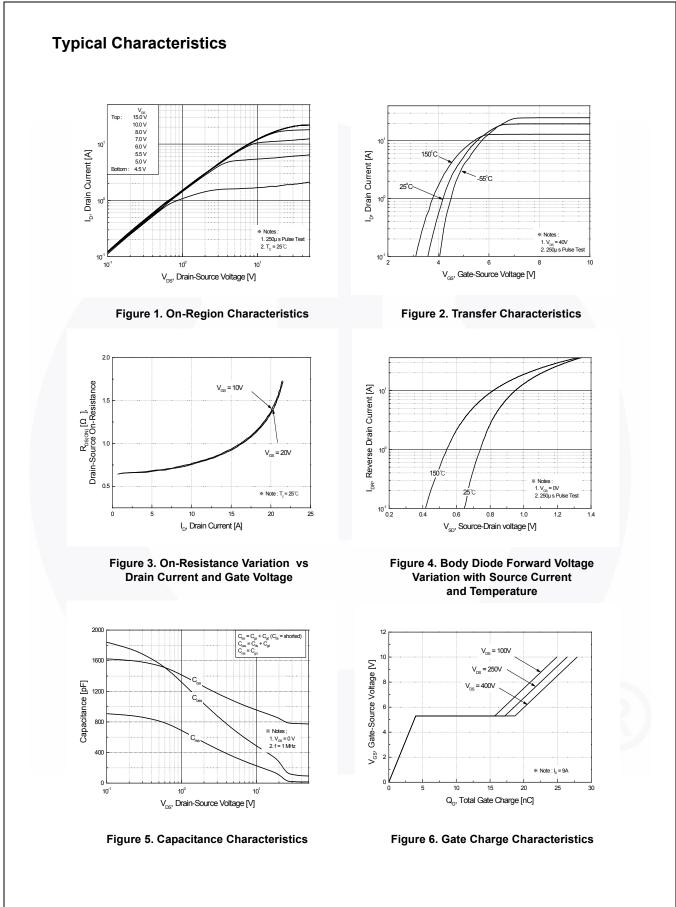
## **Thermal Characteristics**

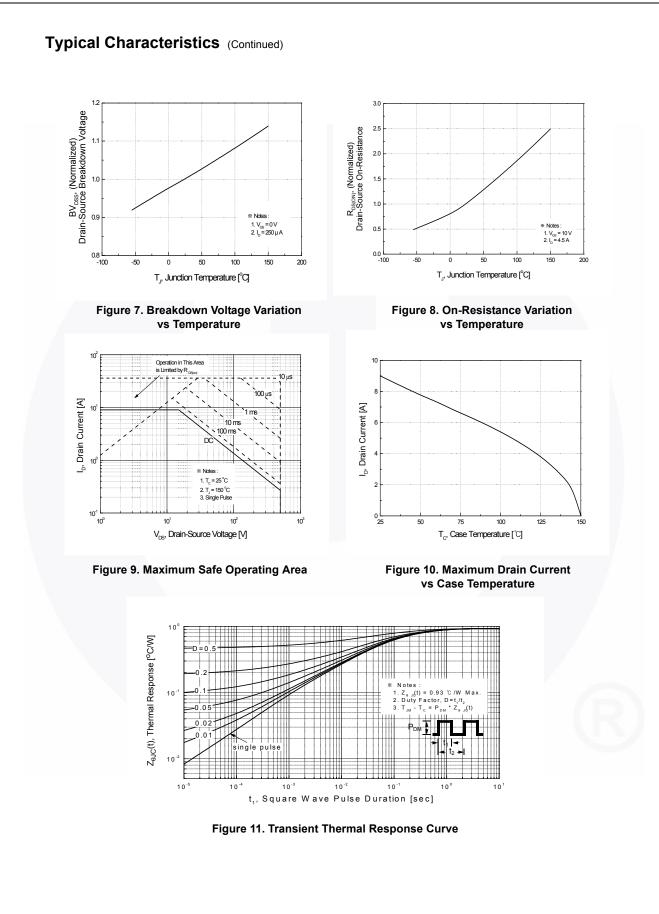
Symbol	Parameter	FQB9N50CTM	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.93	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	C/W	

1

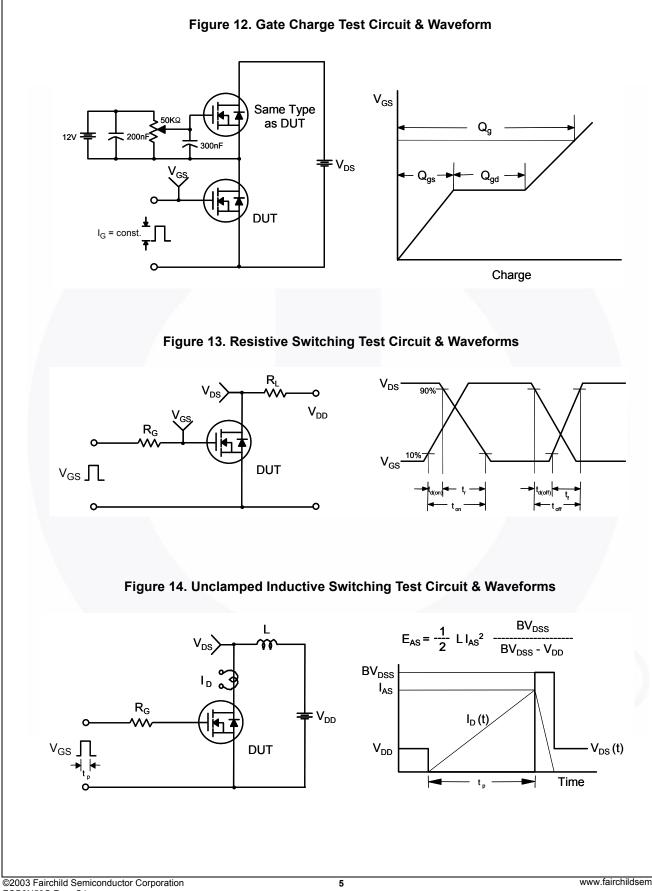
Device MarkingDeviceFQB9N50CFQB9N50CTM		Package Reel Size		Таре	Tape Width		Quantity	
		D <sup>2</sup> -PAK	330 mm	24	24 mm		800 units	
ectri	cal Chara	acteristics T <sub>C</sub> = 25°C	c unless otherwise	noted.				
Symbol		Parameter	Test C	Conditions	Min	Тур	Max	Unit
	rootorioti							
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage		V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA		500			V
ΔBV <sub>DSS</sub>			V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA		500			v
$\Delta DV_{DSS}$	Coefficient	Voltage Temperature	$I_D$ = 250 µA, Referenced to 25°C			0.57		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current		$V_{DS}$ = 500 V, $V_{GS}$ = 0 V				1	μA
022			$V_{DS}$ = 400 V, $T_{C}$ = 125°C				10	μA
GSSF	-	Leakage Current, Forward	$V_{GS}$ = 30 V, $V_{DS}$				100	nA
GSSR	Gate-Body	Leakage Current, Reverse	$V_{GS}$ = -30 V, $V_{DS}$	<sub>S</sub> = 0 V			-100	nA
On Cha	racteristic	s						
V <sub>GS(th)</sub>	Gate Thres	hold Voltage	$V_{DS} = V_{GS}, I_D =$	250 μΑ	2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain On-Resista		V <sub>GS</sub> = 10 V, I <sub>D</sub> =	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		0.65	0.8	Ω
FS		ansconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> =	4.5 A		6.5		S
Dynam C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub>	ic Charact Input Capac Output Cap Reverse Tra	citance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> f = 1.0 MHz	= 0 V,		790 130 24	1030 170 30	pF pF
	ng Charao			_		10	45	
d(on)	Turn-On De Turn-On Ris	,	V <sub>DD</sub> = 250 V, I <sub>D</sub> = 9 A,			18	45 140	ns
r	Turn-Off De		$R_{G} = 25 \Omega$	R <sub>G</sub> = 25 Ω (Note 4)		65 93	140	ns
d(off) f	Turn-Off Fa		-			93 64	195	ns
τ 2 <sub>g</sub>	Total Gate 0			- 0 4		28	35	ns nC
∡g ⊋ <sub>gs</sub>	Gate-Sourc	, and the second	$V_{DS}$ = 400 V, I <sub>D</sub> = 9 A, $V_{GS}$ = 10 V (Note 4)			4		nC
∽gs ⊋ <sub>gd</sub>	Gate-Drain	-				15		nC
				· · · ·				
s		de Characteristics ar Continuous Drain-Source Dic		•			9	A
SM		Pulsed Drain-Source Diode Forward Current				36	A	
/ <sub>SD</sub>		ce Diode Forward Voltage	$V_{GS} = 0 V, I_S = 9 A$				1.4	V
rr		ecovery Time	$V_{GS} = 0 V, I_S = 9 A,$			335		ns
		covery Charge	$dI_{\rm F}$ / $dt = 100  {\rm A/\mu}$			2.95		μC
Q <sub>rr</sub>	Reverse RE							

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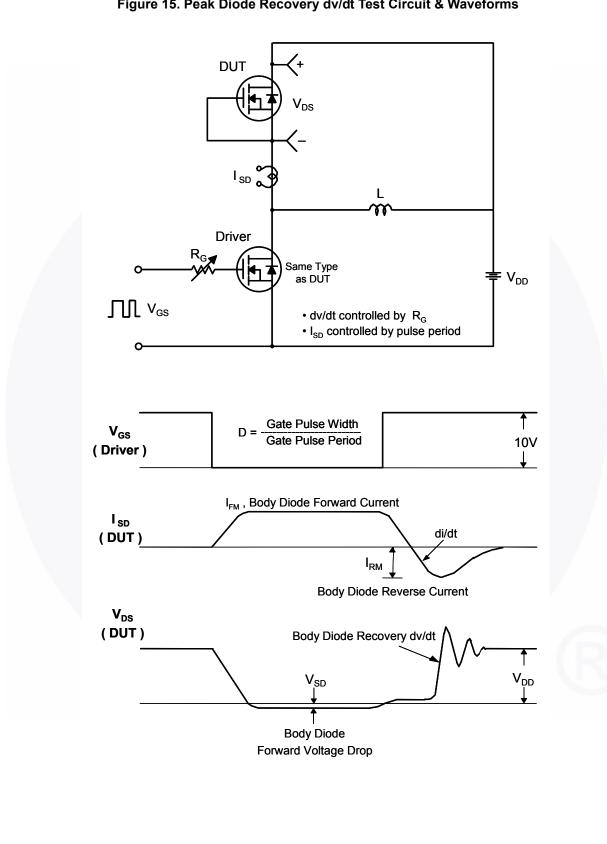
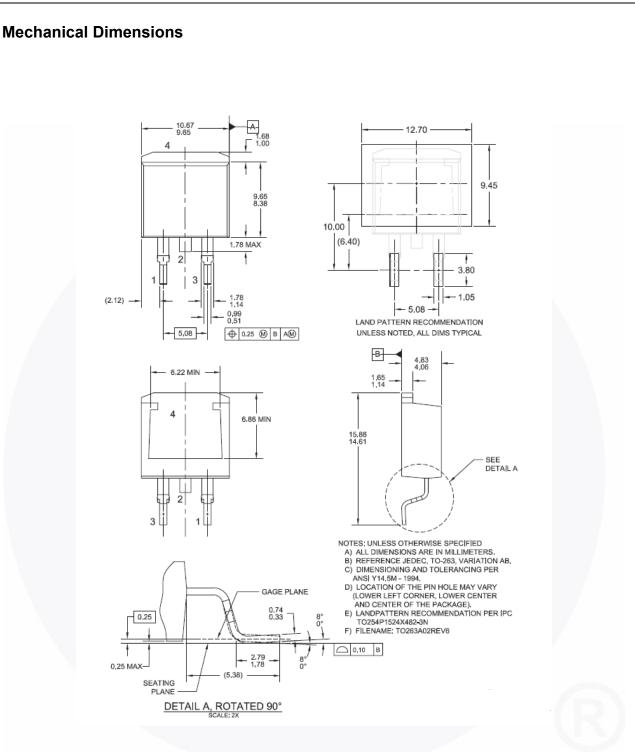


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



## Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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FQB9N50C — N-Channel QFET<sup>®</sup> MOSFET



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EcoSPARK <sup>®</sup>	and Better™	Saving our world, 1mW/W/kW at a time™	TranSiC™
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